


100V PNP HIGH VOLTAGE TRANSISTOR IN SOT23

Features

- $BV_{CEO} > -100V$
- $I_C = -1A$ high Continuous Collector Current
- $I_{CM} = -2A$ Peak Pulse Current
- Low Saturation Voltage
- Excellent h_{FE} Characteristics up to $I_C = -1A$
- Complementary NPN Type: FMMT493
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **PPAP capable (Note 4)**

Mechanical Data

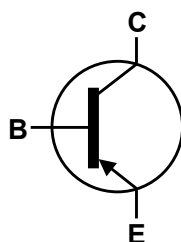
- Case: SOT23
- Case Material: molded plastic, "Green" molding compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 
- Weight 0.008 grams (approximate)

Applications

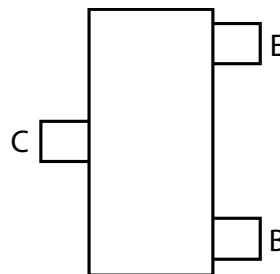
- High-side driver
- Load disconnect switch
- Motor drive



Top View



Device Symbol



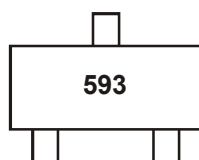
Top View
Pin-Out

Ordering Information (Notes 4 & 5)

| Part Number | Compliance | Marking | Reel size (inches) | Tape width (mm) | Quantity per reel |
|-------------|------------|---------|--------------------|-----------------|-------------------|
| FMMT593TA | AEC-Q101 | 593 | 7 | 8 | 3,000 |
| FMMT593QTA | Automotive | 593 | 7 | 8 | 3,000 |
| FMMT593TC | AEC-Q101 | 593 | 13 | 8 | 10,000 |

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 2. See <http://www.diodes.com> for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified.
 5. For packaging details, go to our website at <http://www.diodes.com>

Marking Information



593 = Product Type Marking Code

Maximum Ratings (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

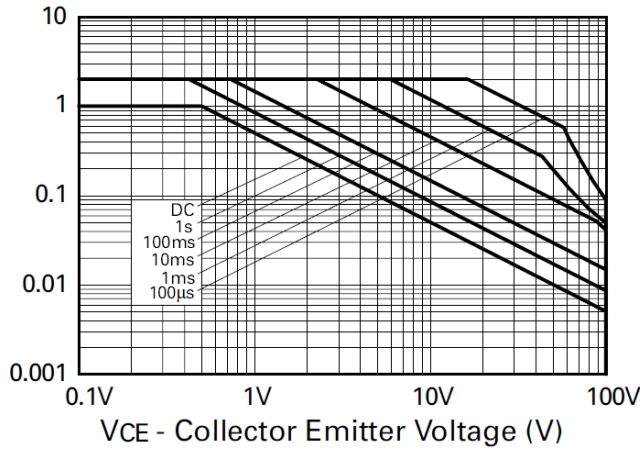
| Characteristic | Symbol | Value | Unit |
|------------------------------|-----------|-------|------|
| Collector-Base Voltage | V_{CBO} | -120 | V |
| Collector-Emitter Voltage | V_{CEO} | -100 | V |
| Emitter-Base Voltage | V_{EBO} | -7 | V |
| Continuous Collector Current | I_C | -1 | A |
| Peak Pulse Current | I_{CM} | -2 | A |
| Continuous Base Current | I_B | -200 | mA |

Thermal Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

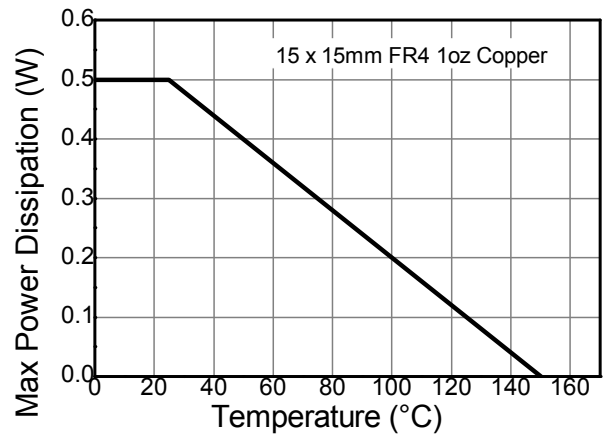
| Characteristic | Symbol | Value | Unit |
|--------------------------------------------------|-----------------|-------------|---------------------------|
| Power Dissipation (Note 6) | P_D | 500 | mW |
| Thermal Resistance, Junction to Ambient (Note 6) | $R_{\theta JA}$ | 250 | $^\circ\text{C}/\text{W}$ |
| Thermal Resistance, Junction to Lead (Note 7) | $R_{\theta JL}$ | 197 | $^\circ\text{C}/\text{W}$ |
| Operating and Storage Temperature Range | T_J, T_{STG} | -55 to +150 | $^\circ\text{C}$ |

- Notes:
6. For a device surface mounted on 15mm X 15mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
 7. Thermal resistance from junction to solder-point (at the end of the collector lead).

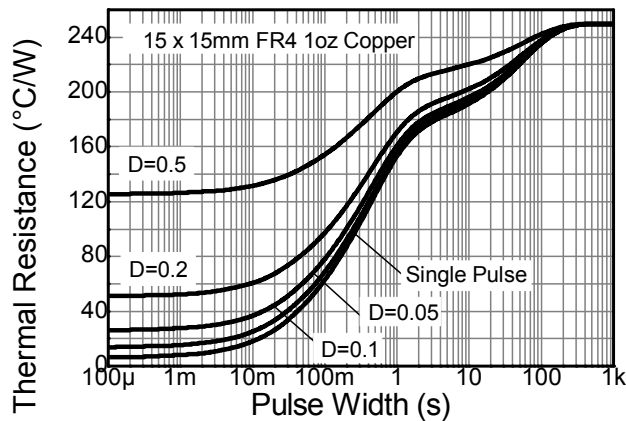
Thermal Characteristics and Derating Information



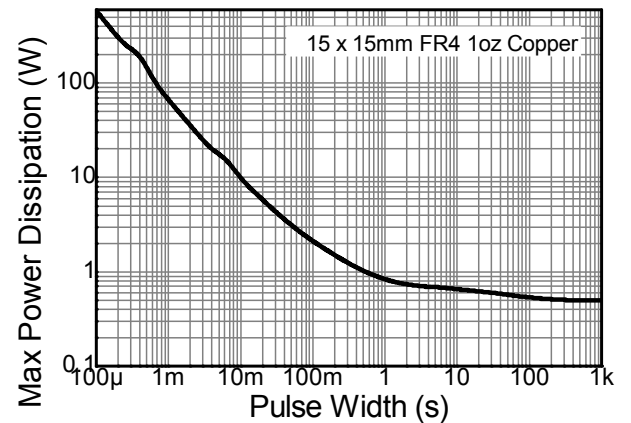
Safe Operating Area



Derating Curve



Transient Thermal Impedance



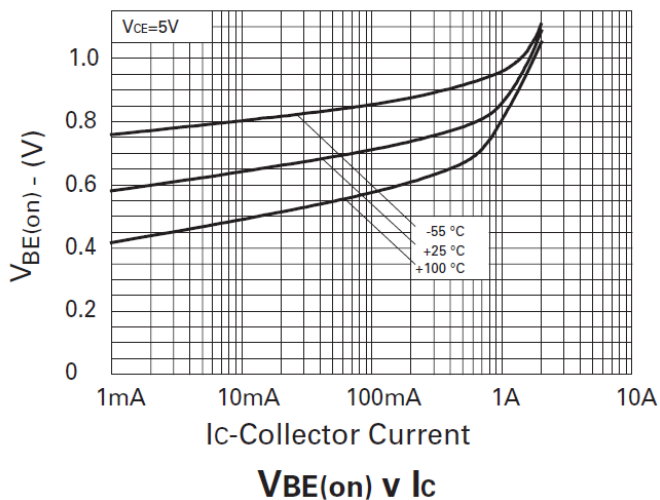
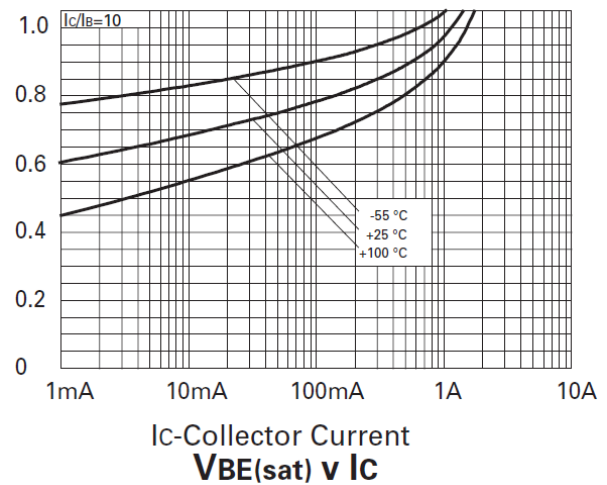
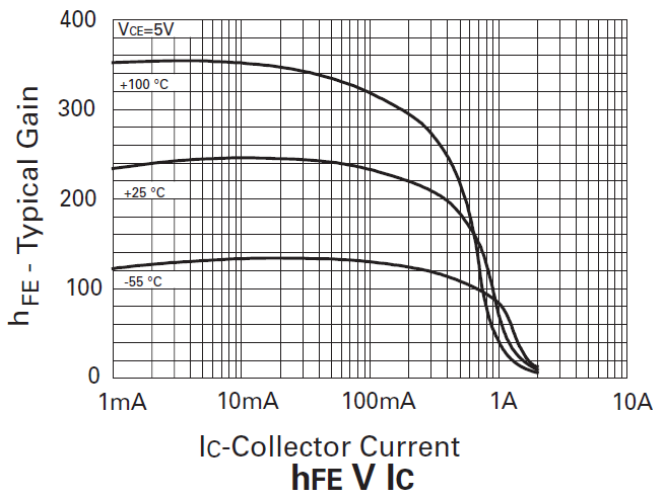
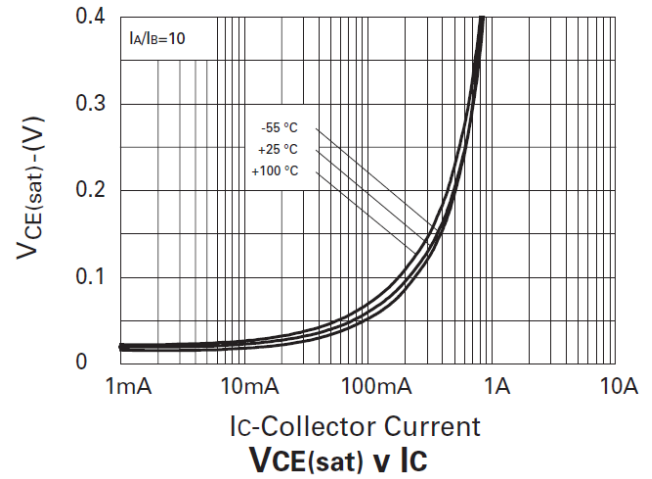
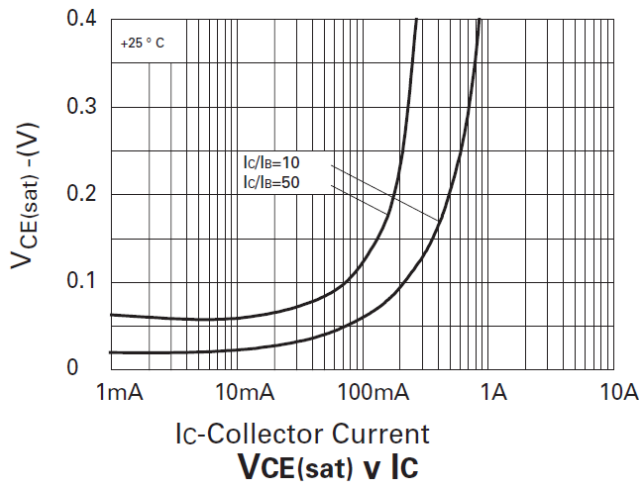
Pulse Power Dissipation

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Typ | Max | Unit | Test Condition |
|------------------------------------------------|----------------------|-------------------------|-----|--------------------|------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| Collector-Base Breakdown Voltage | BV _{CBO} | -120 | — | — | V | I _C = -100μA |
| Collector-Emitter Breakdown Voltage (Note 8) | BV _{CEO} | -100 | — | — | V | I _C = -1mA |
| Emitter-Base Breakdown Voltage | BV _{EBO} | -7 | — | — | V | I _E = -100μA |
| Collector Cutoff Current | I _{CBO} | — | — | -100 | nA | V _{CB} = -100V |
| Emitter Cutoff Current | I _{EBO} | — | — | -100 | nA | V _{EB} = -5.6V |
| Collector-Emitter Cut-Off Current | I _{CES} | — | — | -100 | nA | V _{CES} = -100V |
| Static Forward Current Transfer Ratio (Note 8) | h _{FE} | 100 100 100 50 | — | — — 300 — | — | I _C = -1mA, V _{CE} = -5V I _C = -250mA, V _{CE} = -5V I _C = -500mA, V _{CE} = -5V I _C = -1A, V _{CE} = -5V |
| Collector-Emitter Saturation Voltage (Note 8) | V _{CE(sat)} | — | — | -200 -300 | mV | I _C = -250mA, I _B = -25mA I _C = -500mA, I _B = -50mA |
| Base-Emitter Saturation Voltage (Note 8) | V _{BE(sat)} | — | — | -1.1 | V | I _C = -500mA, I _B = -50mA |
| Base-Emitter Turn-On Voltage (Note 8) | V _{BE(on)} | — | — | -1.0 | V | I _C = -1mA, V _{CE} = -5V |
| Transition Frequency | f _T | 50 | — | — | MHz | V _{CE} = -10V, I _C = -50mA, f = 100MHz |
| Output Capacitance | C _{obo} | — | — | 5 | pF | V _{CB} = -10V, f = 1MHz |

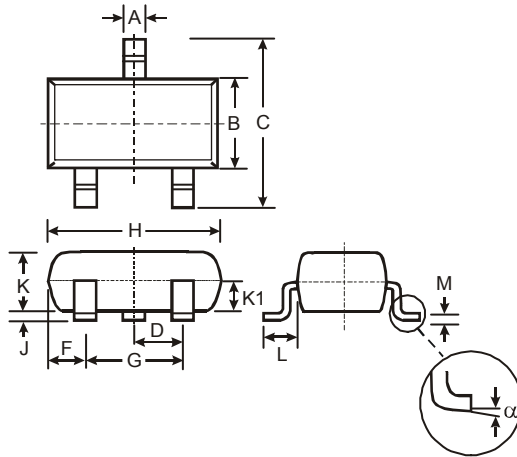
Notes: 8. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)



Package Outline Dimensions

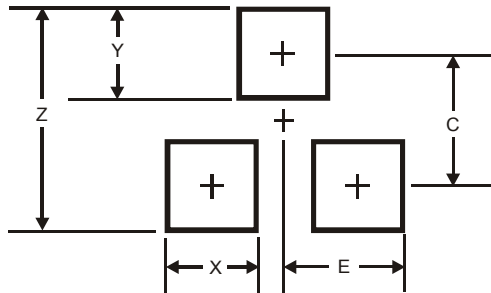
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.



| SOT23 | | | |
|----------------------|-------|------|-------|
| Dim | Min | Max | Typ |
| A | 0.37 | 0.51 | 0.40 |
| B | 1.20 | 1.40 | 1.30 |
| C | 2.30 | 2.50 | 2.40 |
| D | 0.89 | 1.03 | 0.915 |
| F | 0.45 | 0.60 | 0.535 |
| G | 1.78 | 2.05 | 1.83 |
| H | 2.80 | 3.00 | 2.90 |
| J | 0.013 | 0.10 | 0.05 |
| K | 0.903 | 1.10 | 1.00 |
| K1 | - | - | 0.400 |
| L | 0.45 | 0.61 | 0.55 |
| M | 0.085 | 0.18 | 0.11 |
| α | 0° | 8° | - |
| All Dimensions in mm | | | |

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| Z | 2.9 |
| X | 0.8 |
| Y | 0.9 |
| C | 2.0 |
| E | 1.35 |

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